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	SIDDHARTH INSTITUTE OF ENGINEERING & TECHNOLOGV DUTTUD														
	01	DDII			,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		(AU	JTON	OMO	US)	ILCI				
		В	.Tec	h I Ye	ear II :	Seme	ster	Regu	lar Ex	camir	nation	s Oc	tober-2020		
						SEM	ICON	NDUC	TOR	PHY	SICS				
					(Elect	ronics	5 & C	ommu	inicat	ion E	nginee	ring)			
Time	Time: 3 hours May Markey 60														
Time.	5 11	ours			()	\ nouvo	n all E	ivo U		. 1 7 _	60 M	ortza)	Wiux. Wiur	.5. 00	
					(7	Answe	r all F			x 12 =	00 M	arks)			
1	a	Usin	g clas	sical	free el	ectron	theor	v. der	ive an	expre	ession	for el	ectrical conductivity	8M	
		in me	netal.												
	b	Find relaxation time of conduction electron in metal if its resistivity is 1.54×10^{-10} 4													
		and 1	t nas z	0.8X10	28 conc	Juction	i electi	ron/ma	R Give	n m=	9.1 X I	U-31 Kg	$g, e= 1.6 \times 10^{-19} \text{ C}.$		
2	a	Class	sify co	onduc	tor, se	micon	ductor	and i	nsulat	ors ba	sed on	band	theory of solids.	8 M	
	b	Eval	uate l	Fermi	Funct	ion foi	energ	gy <u>K</u> B	Г abov	e Fer	mi lev	el?		4M	
			_			2		UN	IT-II						
3	a	Deriv	ve the	e expi	ession in the	n for c	ce of	t gene electri	rated	due t	o drif	ting o	f charge carriers in	6M	
	b	What is Fermi level? Prove that the Fermi level is lies exactly in between $6N$													
		cond	uction	n band	l and v	alance	e band	of int	rinsic	semic	onduc	tor.	2		
4		D					1 1		OR			1. 1		014	
4	a h	Desc Find	the di	ne cor	istruct	ion an efficier	a wor at of e	king n lectroi	nechar n in Si	118m 0 Lat 30	of Phot 0 K if	0a10a 11. = 0	e. 19 m ² -V ⁻¹ S ⁻¹	δNI 4M	
	U	UNIT-III													
5	a	Deriv	ve Sch	röding	ger's ti	me ind	lepend	lent wa	ave eq	uation				8M	
	b	b Explain the physical significance of wave function.													
6	•	State	and E	vnlair	n Stoka	a's and	Gaus	a'a Th	OR	-9				QЛ/	
0	a b	Expla	and L	npere ³	's law t	throug	h the N	Maxwe	ell equ	s: ations.				οινι 4Μ	
		1		1		U		UN	IT-IV						
7	a	Desc	ribe tl	ne con	structi	on and	work	ing pri	inciple	of He	e-Ne L	aser w	with the help of a neat	9M	
	h	diagr	am.	nnlia	ations	ofIa	ore							3М	
	U	vv 110	e the a	applie	ations	OI Las	5015.		OR					3111	
8	a	a Describe the construction and the working principle of optical fiber.												8M	
	b Mention applications of optical fibers.													4M	
0		- 1				0	G		IT-V						
9	a h	Expla Write	ain the	e conc	ept of	Quanti of nanc	ım Co mater	nfinen ial in i	nent in ndustr	Nano	mater	ials. matior	n technology	6M 6M	
	U	**110		ppnea			mater	1 111 1 (DR	ies an		matio	i termorogy.	UIVI	
10	a	Expla	ain So	l-Gel	technic	que for	synth	esis of	fnanoi	nateri	al.			8 M	
	b	Write	e the a	pplica	tions of	of nanc	mater	ial in v	various	s fields	5.			4M	

*** END ***